

Low-Jitter Precision LVDS Oscillator for Automotive

Features

- Automotive AEC-Q100 Qualified
- Wide Frequency Range: 2.3 MHz to 460 MHz (LVDS)
- Low RMS Phase Jitter: <1 ps (typ.)
- High Stability: ±20 ppm, ±25 ppm, ±50 ppm
- Wide Temperature Range:
 - Automotive Grade 1: -40°C to +125°C
 - Automotive Grade 2: -40°C to +105°C
 - Automotive Grade 3: -40°C to +85°C
- High Supply Noise Rejection: -50 dBc
- Small Industry Standard Footprints
- 2.5 mm x 2.0 mm (VDFN)
- 3.2 mm x 2.5 mm (VDFN & Wettable Flank)
- 5.0 mm x 3.2 mm (CDFN)
- · Excellent Shock and Vibration Immunity
- Qualified to MIL-STD-883
- High Reliability
 - 20x Better MTBF than Quartz Oscillators
- Low Current Consumption
- Supply Range of 2.25 to 3.63V
- Standby and Output Enable Function
- · Lead-Free and RoHS Compliant

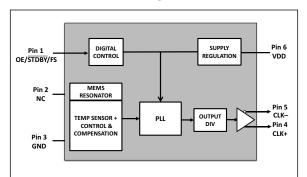
Applications

- · Automotive Infotainment
- Automotive ADAS
- In-Vehicle Networking
- Autonomous Driving

General Description

The DSA1103 and DSA1123 series of high performance oscillators utilize a proven silicon MEMS technology to provide excellent jitter and stability over a wide range of supply voltages and temperatures. By eliminating the need for quartz or SAW technology, MEMS oscillators significantly enhance reliability and accelerate product development, while meeting stringent clock performance criteria for a variety of automotive applications like in-vehicle networking and autonomous driving.

DSA1103 has a standby feature that allows it to completely power-down when pin 1 is pulled low. For DSA1123, only the outputs are disabled when pin 1 is low. Both oscillators are available in industry standard packages, including the small 2.5 mm x 2.0 mm, and are drop-in replacements for standard 6-pin LVDS crystal oscillators.



Functional Block Diagram

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Input Voltage, V _{IN}	–0.3V to V _{DD} +0.3V
Supply Voltage	
ESD Protection (HBM)	
ESD Protection (MM)	
ESD Protection (CDM)	1.5 kV
† Notice: Stresses above those listed under "Absolute Maximum Ratings" may This is a stress rating only and functional operation of the device at those or an	

in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

Electrical Characteristics: V	_{DD} = 3.3V	; T _A = +25°C	unless	otherwise spe	ecified.	
Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Supply Voltage (Note 1)	V _{DD}	2.25	_	3.6	V	—
Supply Current	I _{DD}	_	_	0.095	mA	DSA1103, EN pin low. Output is disabled and device is in standby
		_	20	22		DSA1123, EN pin low, output is disabled
		—	_	±10		Grade 2 and Grade 3 only
		—	_	±20		Includes frequency
Frequency Stability	Δf		_	±25	ppm	variations due to initial
		_	_	±50		tolerance, temp. and power supply voltage.
Aging - First year	Δf _{Y1}		_	±5	ppm	One year @ 25°C
Aging - After first year	Δf _{Y2}	_	_	<±1	ppm/yr	Year two and beyond at +25°C
Startup Time (Note 2)	t _{SU}	_	_	5	ms	T = +25°C
Input Logic Levels	V _{IH}	0.75 x V _{DD}	_	_	V	Input logic high
	V _{IL}	_	_	0.25 x V _{DD}	V	Input logic low
Output Disable Time (Note 3)	t _{DS}	—	_	5	ns	—
Output Enable Time	t _{EN}	_	-	5	ms	DSA1103
				20	ns	DSA1123
Enable Pull-Up Resistor (Note 4)	_	_	40	_	kΩ	Internally pulled-up
LVDS Output						
Supply Current	I _{DD}	_	29	32	mA	Output enabled, $R_L = 100\Omega$
Output Offset Voltage	V _{OS}	1.125	_	1.4	V	R = 100Ω differential
Delta Offset Voltage	ΔV _{OS}	_	_	50	mV	—
Peak-to-Peak Output Swing	V _{PP}	_	350		mV	Single-ended
Output Logic Level High	V _{OH}	0.9 x V _{DD}	_		V	I = ±6 mA
Output Logic Level Low	V _{OL}	—	_	0.1 x V _{DD}	V	
Output Transition Rise Time (Note 3)	t _R	_	200	_	20	20% to 80%, R _L = 50Ω,
Output Transition Fall Time (Note 3)	t _F	_	200		ps	C _L = 2 pF
		2.3	_	460		–40°C to +85°C
Frequency	f _O	3.3	_	460	MHz	–40°C to +105°C and –40°C to +125°C

ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: V_{DD} = 3.3V; T_A = +25°C unless otherwise specified.							
Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions	
Output Duty Cycle	SYM	48	—	52	%	—	
Period Jitter	J _{PER}		2.5		ps _{RMS}	—	
Integrated Phase Noise	J _{PH}	—	0.28	_	ps _{RMS}	200 kHz to 20 MHz @ 156.25 MHz	
		_	0.4	_		100 kHz to 20 MHz @ 156.25 MHz	
		_	1.7	2		12 kHz to 20 MHz @ 125 MHz	

Note 1: Pin 6 V_{DD} should be filtered with 0.1 μ F capacitor.

2: t_{SU} is time to 100 ppm of output frequency after V_{DD} is applied and outputs are enabled.

3: Output Waveform and Test Circuit figures define the parameters.

4: Output is enabled if pad is floated or not connected.

TEMPERATURE SPECIFICATIONS (Note 1)

Parameters	Symbol	Min.	Тур.	Max.	Units	Conditions		
Temperature Ranges								
	T _A	-40	_	+85	°C	Ordering Option I		
Operating Temperature Range (T)	T _A	-40	—	+105	°C	Ordering Option L		
	T _A	-40	_	+125	°C	Ordering Option A		
Junction Operating Temperature	TJ	_		+150	°C	—		
Storage Temperature Range	T _A	-40		+150	°C	—		
Soldering Temperature Range		_		+260	°C	40 sec. max.		
Package Thermal Resistance								
6-Lead VDFN 5.0 mm x 3.0 mm (B)				26		—		
6-Lead VDFN 3.2 mm x 2.5 mm (C)	R _{0JA}	_	_	45	°C/W	—		
6-Lead VDFN 2.5 mm x 2.0 mm (D)		_	—	258		—		

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +150°C rating. Sustained junction temperatures above +150°C can impact the device reliability.

2.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 2-1.

Pin Number	Pin Name	Pin Type	Description			
	OE		Output Enable (DSA1123) H = Specified frequency output. L = Output is high impedance.			
1	STDBY	I	Standby: (DSA1103) H = Specified frequency output. L = Output is high impedance. Device in low power mode; Supply current = I _{STDBY} .			
2	NC	No Connect	Do not connect.			
3	GND	Power	Power supply ground.			
4	CLK+	0	Clock output.			
5	CLK-					
6	VDD	Power	Power supply.			

TABLE 2-1: DSA1103/DSA1123 PIN FUNCTION TABLE

3.0 NOMINAL PERFORMANCE CHARACTERISTICS

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Unless otherwise specified, T = +25°C, V_{DD} = 3.3V.

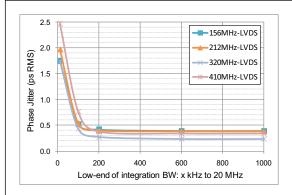


FIGURE 3-1: Phase Jitter (Integrated Phase Noise).

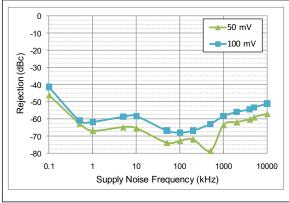
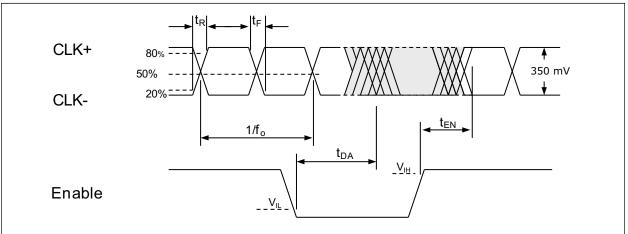
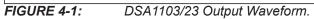


FIGURE 3-2: Power Supply Rejection Ratio.

4.0 OUTPUT WAVEFORM





5.0 TYPICAL TERMINATION SCHEME

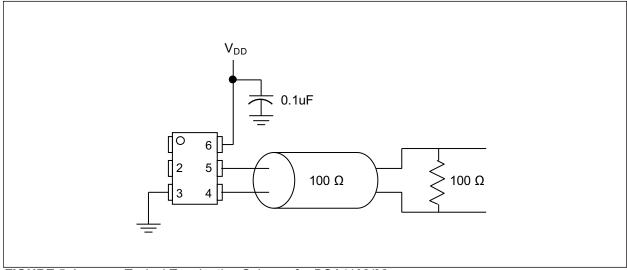


FIGURE 5-1: Typical Termination Scheme for DSA1103/23.

6.0 BOARD LAYOUT (RECOMMENDED)

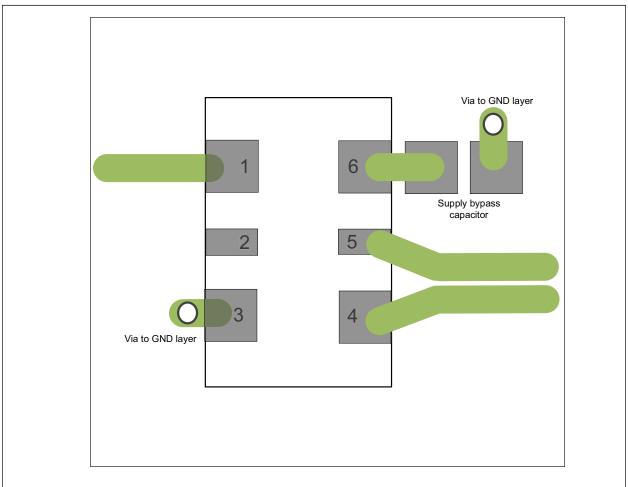
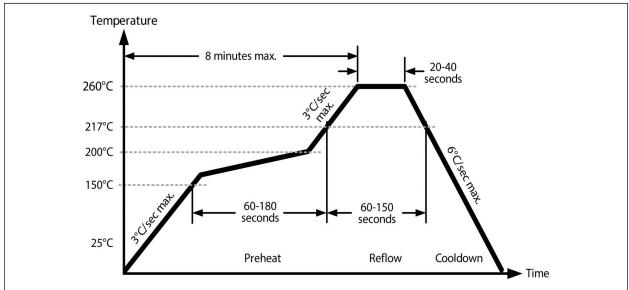


FIGURE 6-1: DSA1103/23 Recommended Board Layout.

Note: Ferrite beads in series with the power supply are not recommended, since they can prevent device start-up by limiting start-up current. If a ferrite bead is used, a tantalum bypass capacitor of at least 20 µF at pin 6 is recommended and correct start-up verified.

7.0 SOLDER REFLOW PROFILE



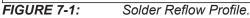
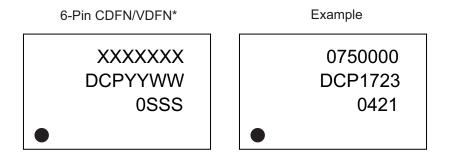


TABLE 7-1: SOLDER REFLOW

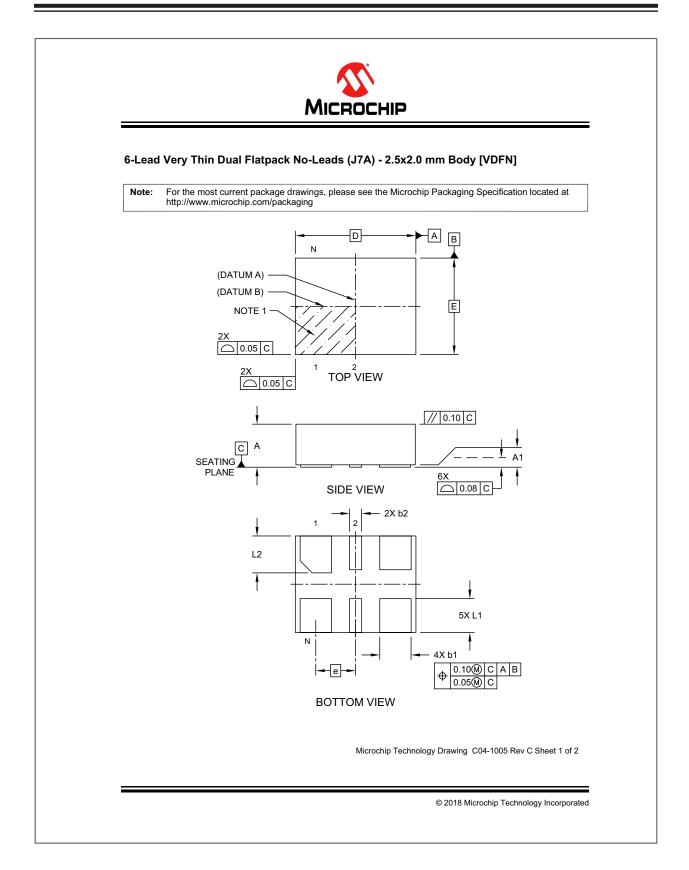
MSL 1 @ 260°C Refer to JSTD-020C						
Ramp-Up Rate (200°C to Peak Temp.)	3°C/sec. max.					
Preheat Time 150°C to 200°C	60 to 180 sec.					
Time Maintained above 217°C	60 to 150 sec.					
Peak Temperature	255°C to 260°C					
Time within 5°C of Actual Peak	20 to 40 sec.					
Ramp-Down Rate	6°C/sec. max.					
Time 25°C to Peak Temperature	8 minutes max.					

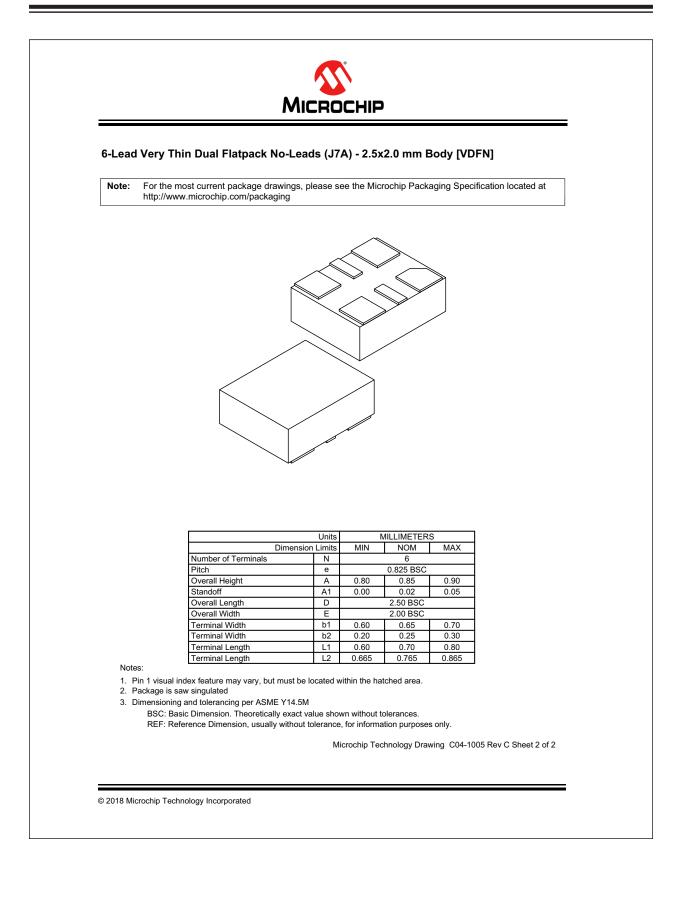
8.0 PACKAGING INFORMATION

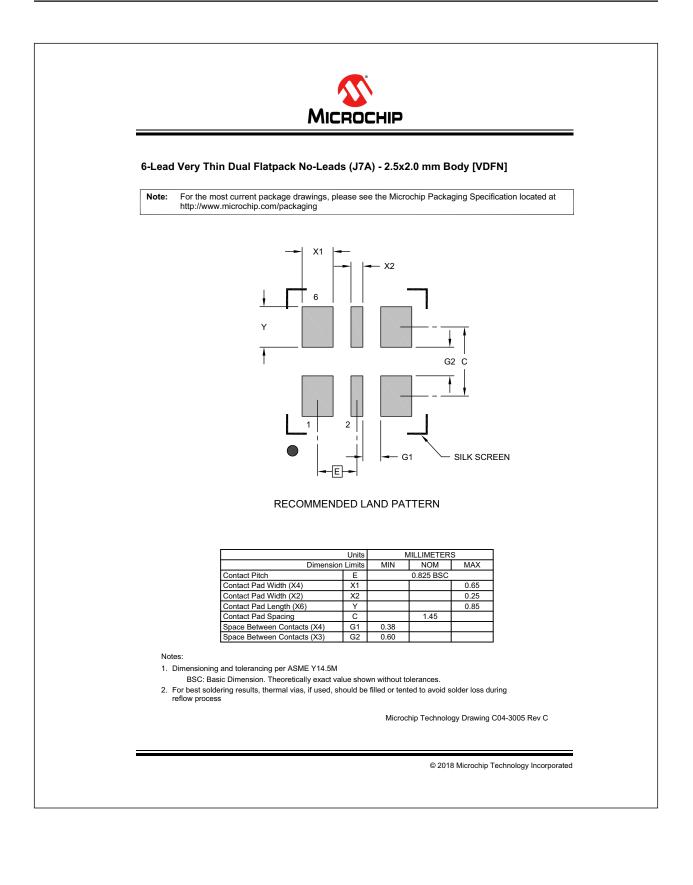
8.1 Package Marking Information

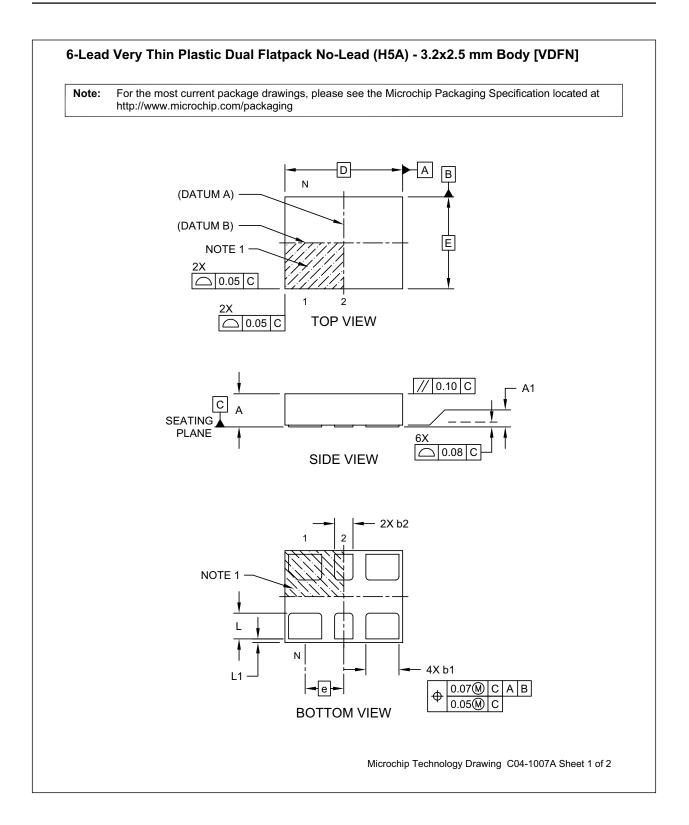


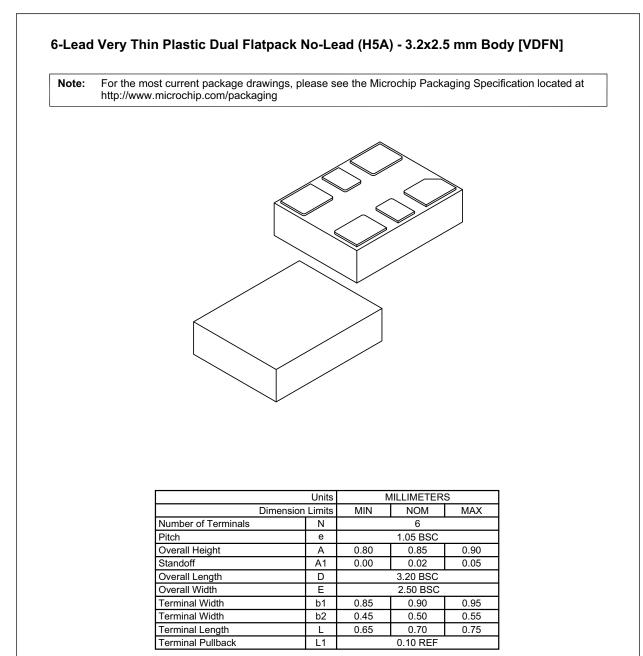
Legend:	XXX Y YY WW NNN €3 * •, ▲, ▼ mark).	Product code, customer-specific information, or frequency in MHz without printed decimal point Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code Pb-free JEDEC [®] designator for Matte Tin (Sn) This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.
	be carried characters the corpor	nt the full Microchip part number cannot be marked on one line, it will d over to the next line, thus limiting the number of available for customer-specific information. Package may or may not include ate logo. (_) and/or Overbar (⁻) symbol may not be to scale.











Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

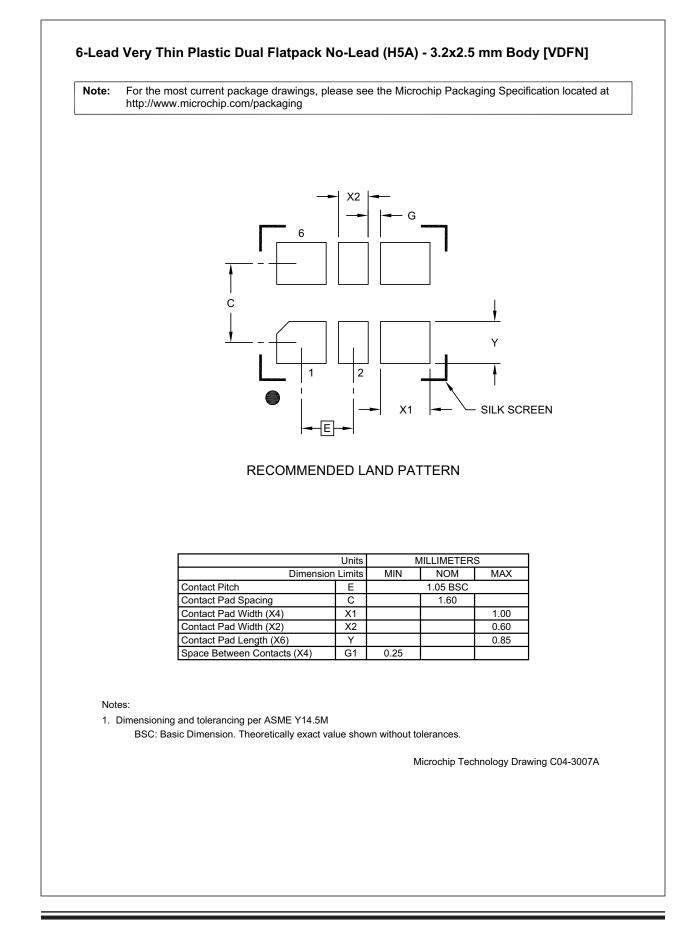
2. Package is saw singulated

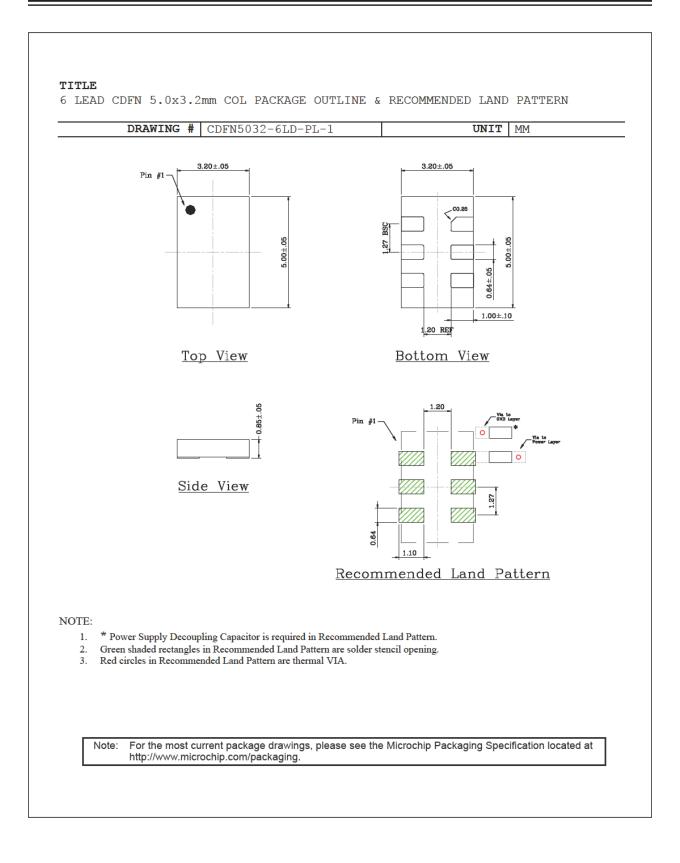
3. Dimensioning and tolerancing per ASME Y14.5M

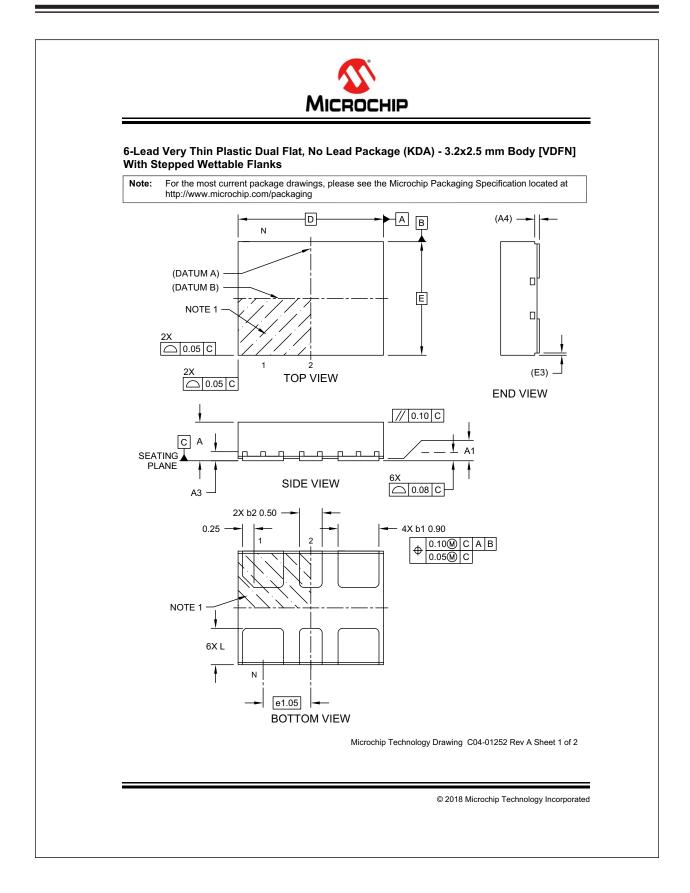
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

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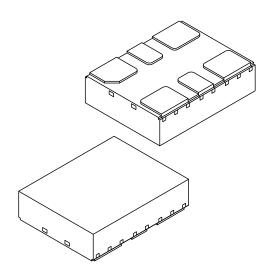






6-Lead Very Thin Plastic Dual Flat, No Lead Package (KDA) - 3.2x2.5 mm Body [VDFN] With Stepped Wettable Flanks

For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging Note:



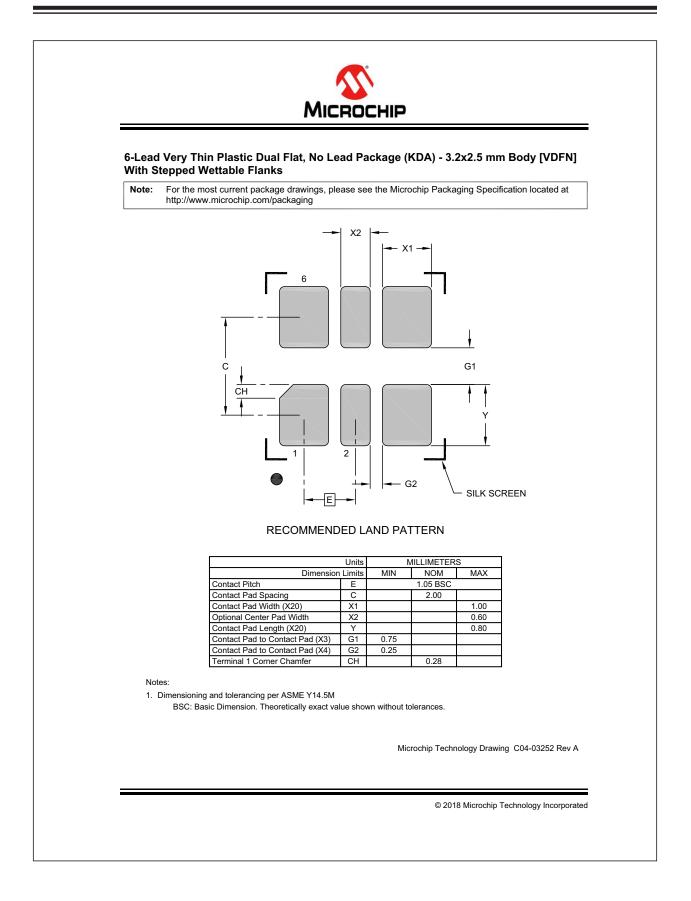
	Units	MILLIMETERS				
Dimensio	Dimension Limits					
Number of Terminals		6				
Pitch	е		1.05 BSC			
Overall Height	Α	0.80	0.85	0.90		
Standoff	A1	0.00	0.02	0.05		
Terminal Thickness	A3	0.15	0.20	0.25		
Overall Length	D	3.20 BSC				
Overall Width	E	2.50 BSC				
Terminal Width	b1	0.85	0.90	0.95		
Terminal Width	b2	0.45	0.50	0.55		
Terminal Length	L	0.70	0.80	0.90		
Step Width	E3		0.05 REF			
Step Height	A4	0.10 REF				

Notes:

Pin 1 visual index feature may vary, but must be located within the hatched area.
Package is saw singulated
Dimensioning and tolerancing per ASME Y14.5M BSC: Basic Dimension. Theoretically exact value shown without tolerances. REF: Reference Dimension, usually without tolerance, for information purposes only.

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NOTES:

APPENDIX A: REVISION HISTORY

Revision A (June 2019)

- Initial release of DSA1103/23 as Microchip data sheet DS20005891A.
- Minor changes throughout the data sheet.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

	X		<u>3</u>	X	X	X	- <u>XXX.</u>	<u>XXXX</u>	X	<u>XXX</u>	
	Enable Modes	(F	Device First 2 Digits)	Package	Temperature Range	Frequency Stability	Frequ	uency	Media Type	Automotive Suffix	
Device:	DSA11	x3:	Low-Jitter Pr Automotive	recision LVDS	S Oscillator for	Example	es:				
Enable Modes:	0 2	=	Enable/Standl Enable/Disabl			a) DSA11 400.0000	TVA0:	for Autom 5x3.2 CD	r Precision LV otive, Enable/ FN, –40°C to 400 MHz, 100	Disable, +85°C,	
Package:	B C D W	= = =	2.0 11111 X 2.0 1	mm VDFN mm VDFN	ettable Flanks)	b) DSA11 074.2500	IVA0:	for Auto 3.2x2.5	omotive, Er	/DS Oscillator nable/Standby, C to +105°C, 00/Tube	
Temperature Range:	A I L	= = =	-40°C to +125 -40°C to +85° -40°C to +105	С		c) DSA11 056.0000	VA0:	0: for Automotive 3.2x2.5 VDFN		recision LVDS Oscillator ive, Enable/Standby, TN (Wettable Flanks), 5°C, ±25 ppm, 56 MHz,	
Stability:	1 2 3	= =	±50 ppm ±25 ppm ±20 ppm			Note 1:	catalog p	part numbe		This identifier	
Frequency Code:	XXX.XXX	x =	2.3 MHz to 46	0 MHz (user-	defined)		the devic Sales Of	ce package	e. Check with ckage availab	is not printed o your Microchip ility with the	
Media Type:	T (blank)	=	1,000/Reel 100/Tube				rape and	u ricei opti	IUII.		
Automotive Suffix:			motive Suffix in ochip.	which "XX" is	s assigned by						

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